



Si photodiode

S12742 series

Photodiode with a filter for monochromatic light (220, 254, 275 nm) detection

The S12742 series uses an interference filter for its window and is sensitive only to monochromatic light. The series consists of three types with different center sensitively wavelengths: 220 nm, 254 nm, and 275 nm. The spectral response half width (FWHM) is extremely narrow at 10 nm (typ.), allowing accurate photometry with little stray light. The S12742 series can be customized to support other peak sensitivity wavelengths such as 340 nm and 560 nm.

Features

Applications

- **■** With monochromatic light filter
- Narrow spectral response half width (FWHM): 10 nm typ.
- **■** Water quality and atmosphere analysis
- UV monitors (mercury lamp, etc.)

Structure

Parameter	Specification	Unit
Package	TO-5	-
Photosensitive area	3.61×3.61	mm

- Absolute maximum ratings

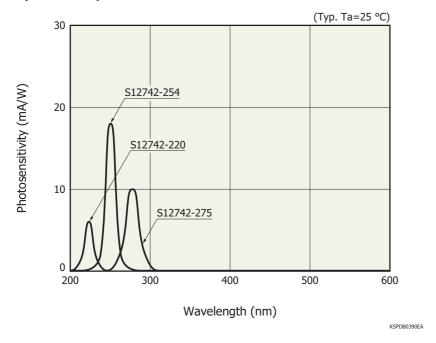
Parameter	Symbol	Condition	Value	Unit
Reverse voltage	VR max	Ta=25 °C	5	V
Operating temperature	Topr		-20 to +60	°C
Storage temperature	Tstg		-55 to +80	°C

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

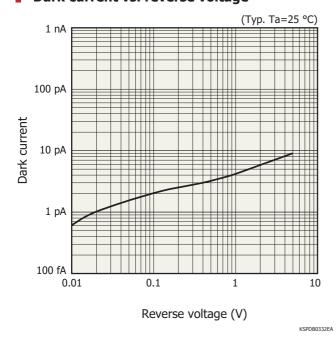
■ Electrical and optical characteristics (Ta=25 °C)

Type no.	Center wavelength CWL		Spectral response half width FWHM		S λ=CWI		l current l	Dark current temperature coefficient	tr VR=0 V	Terminal capacitance Ct VR=0 V	ance resista Rsl		Noise equivalent power NEP VR=0 V		
	Min. (nm)	Typ. (nm)	Max. (nm)			Max. (nm)		Typ.	Max. (pA)	TCID (times/°C)	RL=1 k Ω (µs)	f=10 kHz (pF)	Min. (GΩ)	Typ.	$\lambda = \lambda p$ (W/Hz ^{1/2})
NEW S12742-220	· ,	220	224	6.5	10	13.5	3.8	6	(F)	(,,	(1)	(1-)	(-)	(-)	3.3×10^{-13}
S12742-254	252	254	256	8	10	12	12	18	25	1.12	1	500	0.4	5	9.1×10^{-14}
NEW S12742-275	271	275	279	6.5	10	13.5	6	10							2.0×10^{-13}

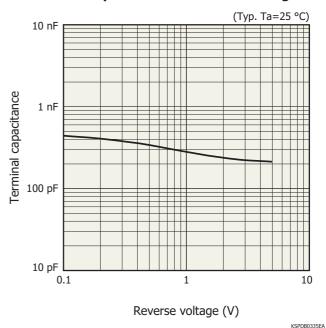
Spectral response



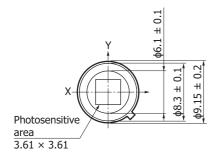
- Dark current vs. reverse voltage

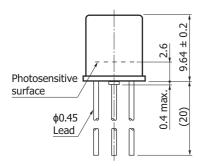


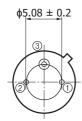
- Terminal capacitance vs. reverse voltage



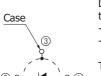
Dimensional outline (unit: mm)







Tolerance unless otherwise noted: ±0.2



Distance from photosensitive area center to cap center $-0.3 \le X \le +0.3$ $-0.3 \le Y \le +0.3$

The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

KSPDA0205EA

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Precautions against UV light exposure

- · When UV light irradiation is applied, the product characteristics may degrade. Such examples include degradation of the product's UV sensitivity and increase in dark current. This phenomenon varies depending on the irradiation level, irradiation intensity, operating time, and operating environment and also varies depending on the product model. Before employing the product, we recommend that you check the tolerance under the ultraviolet light environment that the product will be used in.
- · Exposure to UV light may cause the characteristics to degrade due to gas released from the resin bonding the product's component materials. As such, we recommend that you avoid applying UV light directly on the resin and apply it on only the inside of the photosensitive area by using an aperture or the like.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- · Metal, ceramic, plastic package products
- Technical information
- · Si photodiode / Application circuit examples

Information described in this material is current as of May 2019.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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